1.0 ELECTRICAL CHARACTERISTICS

Absolute Maximum Ratings†

Drain-to-Source Voltage	BV _{DSX}
Drain-to-Gate Voltage	Box
Gate-to-Source Voltage	20,1
Operating Ambient Temperature, T _A	
Storage Temperature, T _S	

† Notice: Stresses above those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress rating only, and functional operation of the device at those or any other conditions above those indicated in the operational sections of this specification is not intended. Exposure to maximum rating conditions for extended periods may affect device reliability.

DC ELECTRICAL CHARACTERISTICS

Electrical Specifications: $T_A = 25^{\circ}$ C unless otherwise specified. All DC parameters are 100% tested at 25°C unless otherwise stated. Pulse test: 300 µs pulse, 2% duty cycle

Parameter	Sym.	Min.	Тур.	Max.	Unit	Conditions
Drain-to-Source Breakdown Voltage	BV _{DSX}	250	_	_	V	$V_{GS} = -5V$, $I_D = 100 \mu A$
Gate-to-Source Off Voltage	V _{GS(OFF)}	-1.5	_	-3.5	V	$V_{DS} = 15V, I_{D} = 1 \text{ mA}$
Change in V _{GS(OFF)} with Temperature	$\Delta V_{GS(OFF)}$	_	_	-4.5	mV/°C	V _{DS} = 15V, I _D = 1 mA (Note 1)
Gate Body Leakage Current	I _{GSS}	_	_	100	nA	V_{GS} = ±20 V, V_{DS} = 0V
Drain to Source Leakage Current		_	_	1	μA	V _{DS} = Maximum rating, V _{GS} = –5V
Drain-to-Source Leakage Current	I _{D(OFF)}	_	_	1	mA	V_{DS} = 0.8 Maximum rating, V_{GS} = -5V, T_A = 125°C (Note 1)
Saturated Drain-to-Source Current	I _{DSS}	300	_	_	mA	V _{GS} = 0V, V _{DS} = 15V
Static Drain-to-Source On-State Resistance	R _{DS(ON)}	_	_	6	Ω	V _{GS} = 0V, I _D = 200 mA
Change in R _{DS(ON)} with Temperature	$\Delta R_{DS(ON)}$	_	_	1.1	%/°C	V _{GS} = 0V, I _D = 200 mA (Note 1)

Note 1: Specification is obtained by characterization and is not 100% tested.

AC ELECTRICAL CHARACTERISTICS

Electrical Specifications: T_A = 25°C unless otherwise specified. Specification is obtained by characterization and is not 100% tested.

Parameter	Sym.	Min.	Тур.	Max.	Unit	Conditions
Forward Transconductance	G _{FS}	225	_	_	mmho	V _{DS} = 10V, I _D = 150 mA
Input Capacitance	C _{ISS}	_	270	350	pF	5.4
Common Source Output Capacitance	C _{OSS}		20	60	pF	$V_{GS} = -5V,$ $V_{DS} = 25V,$ f = 1 MHz
Reverse Transfer Capacitance	C _{RSS}	_	5	20	pF	1 - 1 Will 2
Turn-On Delay Time	t _{d(ON)}	_	_	20	ns	V _{DD} = 25V,
Rise Time	t _r	_	_	25	ns	I _D = 150 mA,
Turn-Off Delay Time	t _{d(OFF)}	_	_	25	ns	$R_{GEN} = 25\Omega$,
Fall Time	t _f	_	_	40	ns	V_{GS} = 0V to -10V
DIODE PARAMETER						
Diode Forward Voltage Drop	V_{SD}	_	_	1.8	٧	V _{GS} = -5V, I _{SD} = 150 mA (Note 1)
Reverse Recovery Time	t _{rr}	_	800	_	ns	$V_{GS} = -5V$, $I_{SD} = 150 \text{ mA}$

Note 1: Unless otherwise stated, all DC parameters are 100% tested at 25°C. Pulse test: 300 μs pulse, 2% duty cycle

TEMPERATURE SPECIFICATIONS

Parameter	Sym.	Min.	Тур.	Max.	Unit	Conditions
TEMPERATURE RANGE						
Operating Ambient Temperature	T _A	-55	_	+150	°C	
Storage Temperature	T _S	-55	_	+150	°C	
PACKAGE THERMAL RESISTANC	E					
3-lead SOT-89	θ_{JA}	_	133	_	°C/W	

THERMAL CHARACTERISTICS

Package	I _D (Note 1) (Continuous) (mA)	I _D (Pulsed) (A)	Power Dissipation at $T_A = 25^{\circ}C$ (Note 2) (W)	I _{DR} (Note 1) (mA)	I _{DRM} (A)
3-lead SOT-89	360	1	1.6	360	1

Note 1: I_D (continuous) is limited by maximum T_J .

2: Mounted on an FR4 board, 25 mm x 25 mm x 1.57 mm

2.0 TYPICAL PERFORMANCE CURVES

Note: The graphs and tables provided following this note are a statistical summary based on a limited number of samples and are provided for informational purposes only. The performance characteristics listed herein are not tested or guaranteed. In some graphs or tables, the data presented may be outside the specified operating range (e.g. outside specified power supply range) and therefore outside the warranted range.

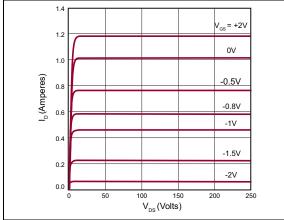


FIGURE 2-1: Output Characteristics.

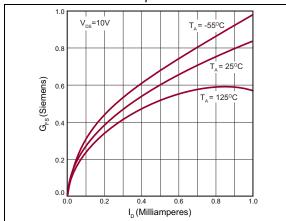


FIGURE 2-2: Transconductance vs. Drain Current.

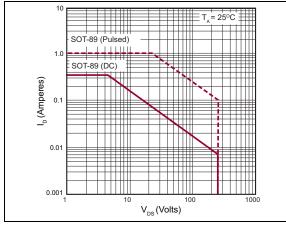


FIGURE 2-3: Maximum Rated Safe Operating Area.

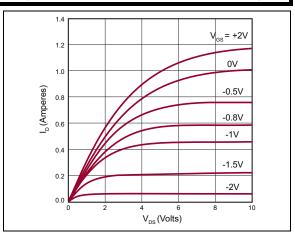


FIGURE 2-4: Saturation Characteristics.

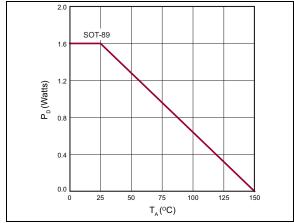


FIGURE 2-5: Power Dissipation vs. Ambient Temperature.

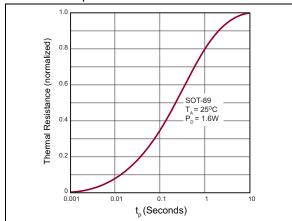


FIGURE 2-6: Thermal Response Characteristics.

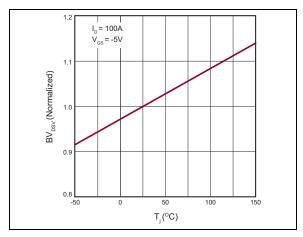


FIGURE 2-7: BV_{DSV} Variation with Temperature.

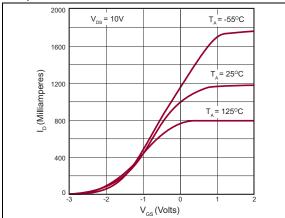


FIGURE 2-8: Transfer Characteristics.

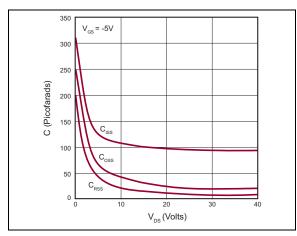


FIGURE 2-9: Capacitance vs. Drain-to-Source Voltage.

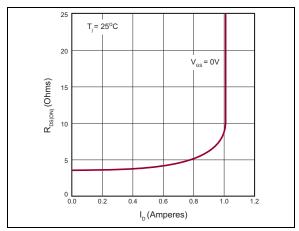


FIGURE 2-10: On-Resistance vs. Drain Current.

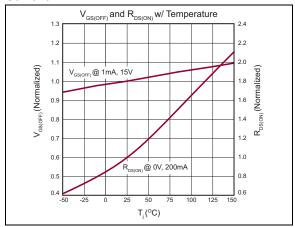


FIGURE 2-11: $V_{GS(OFF)}$ and $R_{DS(ON)}$ with Temperature.

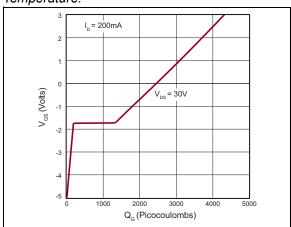


FIGURE 2-12: Gate Drive Dynamic Characteristics.

DN3525

3.0 PIN DESCRIPTION

Table 3-1 shows the description of pins in DN3525. Refer to **Package Type** for the location of pins.

TABLE 3-1: PIN FUNCTION TABLE

Pin Number	Pin Name	Description						
1	Gate	Gate						
2, 4	Drain	Drain						
3	Source	Source						

4.0 FUNCTIONAL DESCRIPTION

Figure 4-1 illustrates the switching waveforms and test circuit for DN3525.

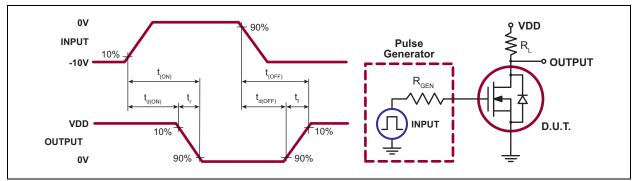


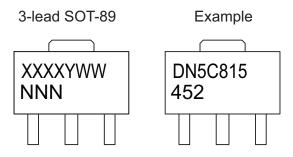
FIGURE 4-1: Switching Waveforms and Test Circuit.

TABLE 4-1: PRODUCT SUMMARY

BV _{DSX} /BV _{DGX} (mA)	R _{DS(ON)} (Maximum) (Ω)	I _{DSS} (Minimum) (mA)
250	6	300

5.0 PACKAGING INFORMATION

5.1 Package Marking Information

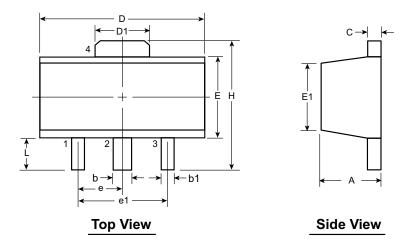


Legend: XX...X Product Code or Customer-specific information
Year code (last digit of calendar year)
YY Year code (last 2 digits of calendar year)
WW Week code (week of January 1 is week '01')
NNN Alphanumeric traceability code

By-free JEDEC® designator for Matte Tin (Sn)
This package is Pb-free. The Pb-free JEDEC designator (a)
can be found on the outer packaging for this package.

Note: In the event the full Microchip part number cannot be marked on one line, it will be carried over to the next line, thus limiting the number of available characters for product code or customer-specific information. Package may or not include the corporate logo.

3-Lead TO-243AA (SOT-89) Package Outline (N8)



Note: For the most current package drawings, see the Microchip Packaging Specification at www.microchip.com/packaging.

Symbo	ol	Α	b	b1	С	D	D1	E	E1	е	e1	Н	L
	MIN	1.40	0.44	0.36	0.35	4.40	1.62	2.29	2.00 [†]			3.94	0.73 [†]
Dimensions (mm)	NOM	-	-	-	-	-	-	-	-	1.50 BSC	3.00 BSC	-	-
()	MAX	1.60	0.56	0.48	0.44	4.60	1.83	2.60	2.29		_ 30	4.25	1.20

JEDEC Registration TO-243, Variation AA, Issue C, July 1986.
† This dimension differs from the JEDEC drawing

Drawings not to scale.

DN3525

NOTES:

APPENDIX A: REVISION HISTORY

Revision A (May 2018)

- Converted Supertex Doc# DSFP-DN3525 to Microchip DS20005705A
- Added a pin function table
- · Changed the package marking format
- Made minor text changes throughout the document

PRODUCT IDENTIFICATION SYSTEM

 $\underline{\text{To order or obtain information, e.g., on pricing or delivery, contact your local Microchip representative or sales office.}\\$

PART NO.	<u> </u>		- <u>X</u> - <u>X</u>	Example:	
Device	Packa Optio		Environmental Media Type	a) DN3525N8-G:	N-Channel Depletion-Mode Vertical DMOS FET, 3-lead SOT-89, 2000/Reel
Device:	DN3525	=	N-Channel Depletion-Mode Vertical DMOS FET		
Package:	N8	=	3-lead SOT-89		
Environmental:	G	=	Lead (Pb)-free/RoHS-compliant Package		
Media Type:	(blank)	=	2000/Reel for an N8 Package		

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